	Туре	L #	Hits	Search Text	DBs
1	BPS	L1	319780	257/\$.ccls. 438/\$.ccls.	USPAT; US-PGPUB; EPO; JFO; DERWENT; IBM_TEB
2	PFS	L2	9461	<pre>l and (TFT or TFT-LCT or (thin near film near transistor))</pre>	USPAT; US-PGPUB; EPO; [JPO; DERWENT; IBM_TOB
3	EFS	ئيا	4.5	2 and (fourth near photolithography)	UNPAT; US-PGPUB; EFO; UPO; DERWENT; IBM_TOB
4	EFS	L5		koh yashi-kamihir r hakamura-hobuhir of inoue-kazunori or yoshida-takuji or nakashima-ken or masutani-yuichi or aoki-hironori).in.	USPAT; US-PGPUE; EFI; JPO; DEFWENT; IBM_TEE
Ē.	BES	1.6	104	<pre>[5 and STET or TET-LMC or ] [(thin near film near ;transistor))</pre>	UMPAT; US-HGPUE; EPI; JFO; DERWENT; IBM_TDB
ť,	BFS	I.7	5	6 and (fourth near photolithography)	USPAT; US-PGPUE; EPG; JPO; DERWENT; IEM_TEE
	BF.S	L8	16779	(TFT or TFT-LOD on (thin near film near transistor), .ti.	USPAT; US-PGPUE; EPD; Cho; DERWENT; 18M_TUE
÷	BES	L9	45	<pre>8 and (fourth near photolithography)</pre>	USPAT; US-PGPUB; EFI; USO; DERWENT; IEM_TUB
	bit.si	μιυ		near hole)	JPO; DERWENT; IEM_TOE
10	B.F.S	L11	44838	(TFT or TFT-LCD or (thin near film near transistor);	USPAT; US-PGPUE; EPD; JPO; DERWENT; IEM_TDE
11	BRS	L12	91	11 and (fourth near photolithography)	USPAT; US-PGPUB; EPD; JPO; DERWENT; IEM_TOB
10	BRS		î   6	10 and /hontact near Hile:	USPAT; US-PGPUB; EPO; JIO; DERWENT; IBM_TDB